

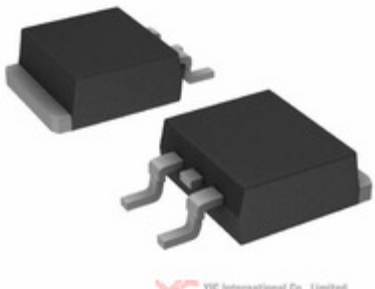




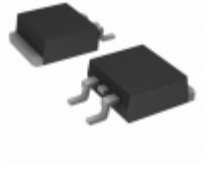



	<p>IPB65R225C7ATMA1</p>
	<p>Manufacturer Part Number: IPB65R225C7ATMA1</p> <p>Manufacturer/Brand: International Rectifier (Infineon Technologies)</p> <p>Part of Description: MOSFET N-CH 650V 11A TO-263-3</p> <p>Datasheets:  IPB65R225C7ATMA1.pdf</p> <p>RoHs Status:  Lead free / RoHS</p> <p>Stock Condition: Compliant New original, Stock Available.</p> <p>Ship From: Hong Kong</p> <p>Shipment Way: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Specifications

Part Number	IPB65R225C7ATMA1
Manufacturer	International Rectifier (Infineon Technologies)
Description	MOSFET N-CH 650V 11A TO-263-3
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	Require For Quote & Check Stock
Vgs(th) (Max) @ Id	4V @ 240µA
Vgs (Max)	±20V
Technology	MOSFET (Metal Oxide)
Supplier Device Package	PG-TO263
Series	CoolMOS™ C7
Rds On (Max) @ Id, Vgs	225 mOhm @ 4.8A, 10V
Power Dissipation (Max)	63W (Tc)
Packaging	Tape & Reel (TR)
Package / Case	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Input Capacitance (Ciss) (Max) @ Vds	996pF @ 400V
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
FET Type	N-Channel
FET Feature	-
Drive Voltage (Max Rds On, Min Rds On)	10V
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	11A (Tc)

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 <p>IPB65R190CFDAATMA1 Infineon Technologies MOSFET N-CH TO263-3</p>	 <p>IPB65R190CFD Infineon Technologies IPB65R190CFD Infineon Technologies</p>	 <p>IPB65R280C6ATMA1 Infineon Technologies MOSFET N-CH 650V 13.8A TO263</p>	 <p>IPB65R190C7ATMA2 International Rectifier (Infineon Technologies) MOSFET N-CH TO263-3</p>

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